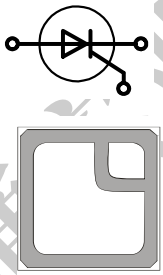
IXYS Thyristor Chip CWP 8-12

preliminary

Type	Ag* Al*	V_{DRM} / V_{RRM}	V_{DSM} / V_{RSM} [V]	$I_{T(AV)}$ [A]	Chip Size [mm] x [mm]	Package Options
CWP 8-12	☑ ☑	1200	1300	23	5.20 5.20	sawn on foil ☑ unsawn wafer ☑ * in waffle pack ☑

*Frontside options

*Please contact IXYS chip sales



Mechanical Parameters

Area active	0.12	cm^2	
Area total	0.27	cm^2	
Wafer size Ø	150	mm	
Thickness	290	µm	
Material	Si		
Max. possible chips per wafer	498		
Passivation front side	Glassivation		
Metallization top side	solderable: Ti / Ni / Ag *		
top side	bondable: Al		
Recom. wire bonds (Al)	Cathode	Gate	
Number / Ø [µm]	5 / 300	1 / 300	
Metallization backside	solderable (only): Ti / Ni / Ag *		
Reject Ink Dot Size	Ø 0.4-1.0	mm	
Recom. Storage Environment			
sawn on foil	in org. container, in dry nitrogen	< 6	month
unsawn wafer	in org. container, in dry nitrogen	< 2	year
in waffle pack	in org. container, in dry nitrogen	< 2	year
	T_{stg}	-40 ... 40	°C

*Sinterable top/bottom side on request

Features

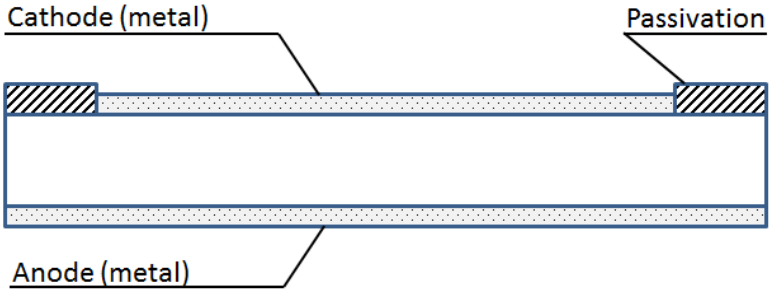
- planar passivated with guardring and channelstopper
- Planar front and back surface
- Non-structured anode contact on full area bottom side

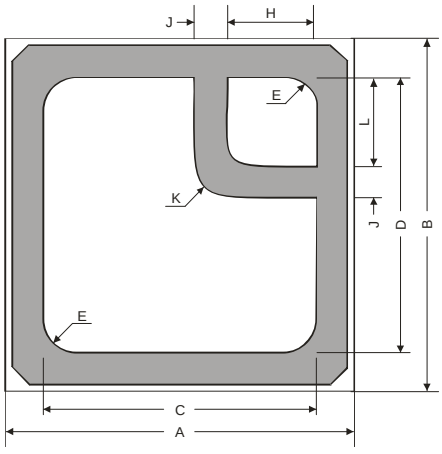
Applications

- DC motor control
- AC power control
- Softstart AC motor controller
- Light, heat and temperature control

Dimensions

A [mm]	B [mm]	C [mm]	D [mm]	E [mm]
5.20	5.20	3.70	3.70	0.34





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Electrical parameters

Symbol	Conditions		Ratings min.	typ.	max.	
I_R	V_D = Vr = Vrr	T_{VJ} = 25°C			0.05	mA
		T_{VJ} = 150°C			4	mA
V_T	I_T = 44 A	T_{VJ} = 25 °C			1.53	V
		T_{VJ} = 150 °C			1.55	V
V_{T0}	For power-loss calculations only				0.92	V
r_T	T_{VJ} = 150 °C				14.00	mΩ
V_{GT}	V_D = 6 V	T_{VJ} = 25°C			2.5	V
		T_{VJ} = -40°C			3.5	V
I_{GT}	V_D = 6 V	T_{VJ} = 25°C	11		28	mA
		T_{VJ} = -40°C			50	mA
V_{GD}	T_{VJ} = 150 °C	V = ⅔ V_{DRM}			0.2	V
I_{GD}					1	mA
I_L	t_p = 10 µs	T_{VJ} = 25°C I_G = 0.2 A di_G/dt = 0.2 A/µs			100	mA
I_H	R_{GK} = ∞	T_{VJ} = 25°C V_D = 6 V			80	mA
t_{gd}	V_D = ½ V_{DRM}	T_{VJ} = 25°C			2	µs
	I_G = 0.5 A	di_G/dt = 0.5 A/µ				
t_q	V_R = 100 V	I_T = 23 A -di/dt = 10 A/µs			150	µs
	t_p = 200 µs	dv/dt = V/µs V_D = ⅔ Vdrm T_{VJ} = 125 °C				
$(di/dt)_{cr}$	repetitive	I_T = 40 A			150	A/µs
	non repetitive	I_T = 23 A			500	A/µs
	V = ⅔ V_{DRM}	T_{VJ} = 150 °C di_G/dt = 0.2 A/µs				
	I_G = 0.2 A	t_p = 200 µs f = 50 Hz				
$(dv/dt)_{cr}$	T_{VJ} = 150 °C	V_{DR} = ⅔ V_{DRM}			200	V/µs
	R_{GK} = ∞	method 1 (linear voltage rise)				
P_{GM}	T_{VJ} = 150 °C	t_p = 30 µs			10	W
		t_p = 3E µs			5	W
P_{GAV}					0.5	W
V_{RGM}					10	V
T_{VJ}			-40		150	°C
$I_{T(AV)}$	T_C = 100 °C	180° rect.			23	A
	T_{VJ} = 150 °C	180° sine			22	A
I_{TSM} *	T_{VJ} = 45°C	t = 10 ms (50) Hz, sine			300	A
	V_R = 0 V	t = 8.3 ms (60) Hz, sine			320	A
	T_{VJ} = 150 °C	t = 10 ms (50) Hz, sine			240	A
	V_R = 0 V	t = 8.3 ms (60) Hz, sine			260	A
I^2t *	T_{VJ} = 45°C	t = 10 ms (50) Hz, sine			450	A^2s
	V_R = 0 V	t = 8.3 ms (60) Hz, sine			425	A^2s
	T_{VJ} = 150 °C	t = 10 ms (50) Hz, sine			288	A^2s
	V_R = 0 V	t = 8.3 ms (60) Hz, sine			281	A^2s
R_{thJC} *	DC current			1.4		K/W

* Data according to assembled product tbd

Data according to IEC 60747

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- the conclusion of quality agreements;

- to establish joint measures to ensure application specific product capabilities and notify that IXYS may delivery dependent on the realization of any such measures.